



50 MHz to 850 MHz, CASCADABLE

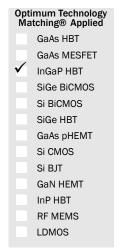
Package: SOT-89

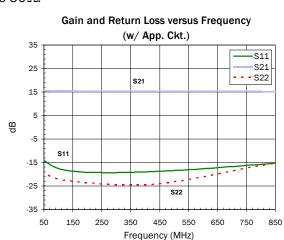




#### **Product Description**

RFMD's SBB1089Z is a high performance InGaP HBT MMIC amplifier utilizing a Darlington configuration with an active bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 5V supply, the SBB1089Z does not require a dropping resistor as compared to typical Darlington amplifiers. The SBB1089Z product is designed for high linearity 5V gain block applications that require small size and minimal external components. It is internally matched to  $50\,\Omega$ .





#### **Features**

- OIP<sub>3</sub>=43.1dBm at 240MHz
- P<sub>1dB</sub>=19.6dBm at 500MHz
- Single Fixed 5V Supply
- Robust 1000V ESD, Class 1C
- Patented Thermal Design and Bias Circuit
- Low Thermal Resistance

### **Applications**

- Receiver IF Amplifier
- Cellular, PCS, GSM, UMTS
- Wireless Data, Satellite Terminals

Doughastan		Specification		Unit	O andikian
Parameter	Min.	Тур.	Max.		Condition
Small Signal Gain		15.5		dB	70MHz
	14.0	15.5	17.0	dB	240 MHz
	14.0	15.5	17.0	dB	400 MHz
Output Power at 1dB Compression		19.0		dBm	70MHz
		19.0		dBm	240 MHz
	18.0	19.0		dBm	400 MHz
Third Order Intercept Point		42.0		dBm	70MHz
		43.0		dBm	240 MHz
	38.5	40.5		dBm	400MHz
Return Loss		50 to 850		MHz	Minimum 10dB
Input Return Loss	14.0	18.0		dB	70 MHz to 5000 MHz
Output Return Loss	12.0	16.0		dB	70 MHz to 5000 MHz
Noise Figure		3.5	4.2	dB	500MHz
Reverse Isolation		18.0		dB	70MHz to 5000MHz
Thermal Resistance		48.8		°C/W	junction - lead
Device Operating Voltage		5.0	5.3	V	
Device Operating Current	82.0	90.0	98.0	mA	

 $\textbf{Test Conditions: V}_{D} = \textbf{5V, I}_{D} = \textbf{90 mA Typ., OIP}_{3} \textbf{ Tone Spacing} = \textbf{1MHz, P}_{OUT} \textbf{ per tone} = \textbf{0 dBm, T}_{L} = \textbf{25 °C, Z}_{S} = \textbf{Z}_{L} = \textbf{50}\Omega, \textbf{ Tested with Bias Tees Pour Per tone} = \textbf{0 dBm, T}_{L} = \textbf{25 °C, Z}_{S} = \textbf{Z}_{L} = \textbf{50}\Omega, \textbf{25 conditions} = \textbf{25 °C, Z}_{S} = \textbf{25 °C, Z$ 

# **SBB1089Z**



#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Device Current (I <sub>D</sub> )	110	mA
Device Voltage (V <sub>D</sub> )	5.5	V
RF Input Power	24	dBm
Junction Temp (T <sub>J</sub> )	+150	°C
Operating Temp Range (T <sub>L</sub> )	-40 to +85	°C
Storage Temp	+150	°C
Power Dissipation	0.61	W
ESD Rating - Human Body Model (HBM)	Class 1C	
Moisture Sensitivity Level	MSL2	

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:  $I_DV_D \! < \! (T_J \! - \! T_L) / R_{TH}, j \! - \! l \text{ and } T_L \! = \! T_{LEAD}$ 



#### Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

Typical RF Performance at Key Operating Frequencies (With 240MHz Application Circuit)

Parameter	Unit	50MHz	70MHz	100	240	400	500	850
				MHz	MHz	MHz	MHz	MHz
Small Signal Gain, S <sub>21</sub>	dB	16.0	15.5	15.5	15.5	15.5	15.5	15.0
Output Third Order Intercept Point, OIP <sub>3</sub>	dBm	41.5	42.0	43.0	43.0	41.0	40.0	35.0
Output Power at 1dB Compression, P <sub>1dB</sub>	dBm	19.0	19.0	19.0	19.0	19.0	19.0	18.0
Input Return Loss, S <sub>11</sub>	dB	13.0	16.0	17.0	19.0	19.0	18.0	15.0
Output Return Loss, S <sub>22</sub>	dB	18.0	20.0	21.0	23.0	24.0	23.0	17.0
Reverse Isolation, S <sub>12</sub>	dB	18.0	18.0	18.0	18.0	18.0	18.0	18.0
Noise Figure, NF	dB	3.5	3.3	3.2	3.1	3.2	3.2	3.4

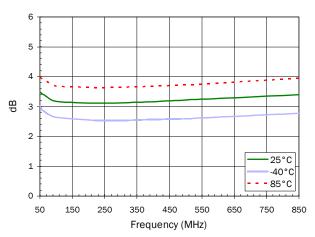
 $\begin{tabular}{ll} Test Conditions: $V_{CC}=5V$ & $I_D=90\,\text{mA Typ.}$ & $OIP_3$ Tone Spacing = 1MHz, $P_{OUT}$ per tone = 0dBm $T_L=25\,^{\circ}C$ & $Z_S=Z_L=50\Omega$ & $I_D=20\,^{\circ}C$ & $I_D=20\,^{\circ}$ 



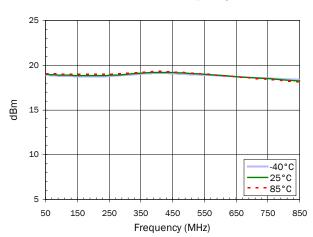


Data on Charts taken with 240 MHz App. Ckt.

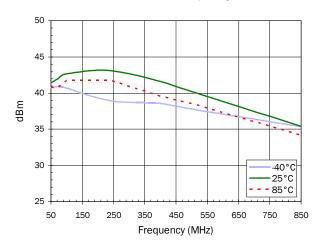
#### Noise Figure versus Frequency



#### P1dB versus Frequency



#### **OIP3** versus Frequency

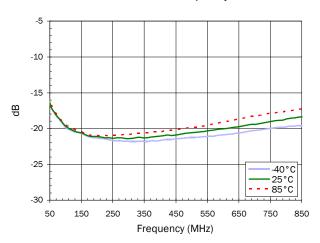


# **SBB1089Z**

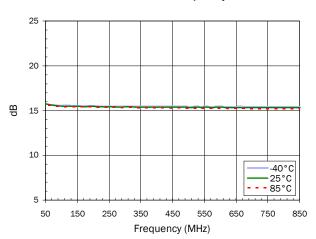


#### S-Parameters over Temperature (Bias Tee)

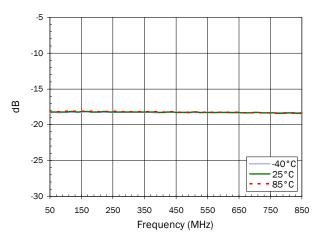
#### S11 versus Frequency



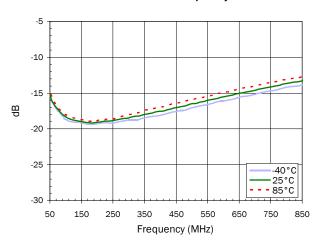
#### S21 versus Frequency



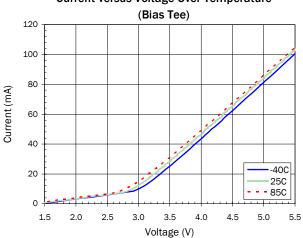
#### S12 versus Frequency



#### S22 versus Frequency



#### **Current versus Voltage Over Temperature**

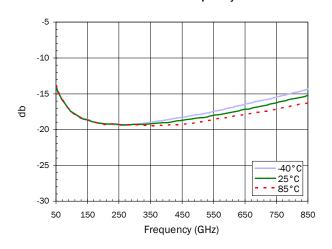




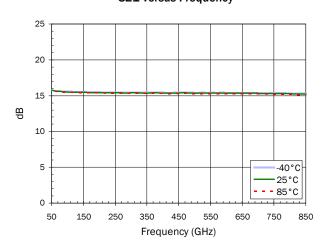


#### 240 MHz Application Circuit S-Parameters over Temperature

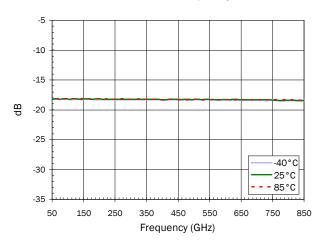
#### **S11** versus Frequency



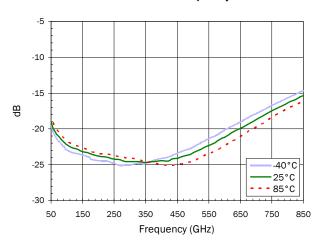
#### S21 versus Frequency



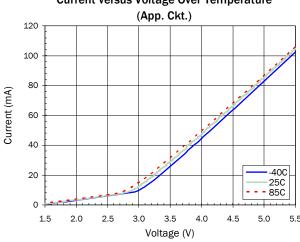
#### S12 versus Frequency



#### S22 versus Frequency



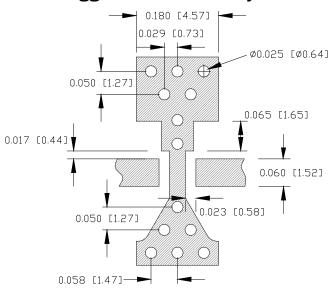
#### **Current versus Voltage Over Temperature**





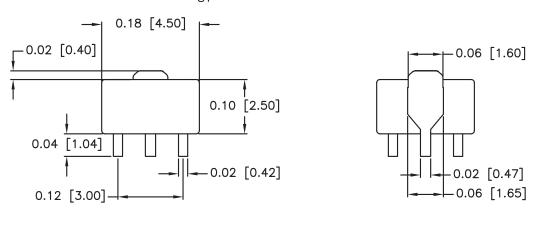
Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
3	RF OUT/BIAS	RF output and bias pin. DC voltage is present on tis pin, therefore a DC blocking capacitor is necessary for proper operation.

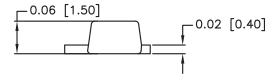
## **Suggested PCB Pad Layout**



### **Package Drawing**

Dimensions in inches (millimeters)
Refer to drawing posted at www.rfmd.com for tolerances.



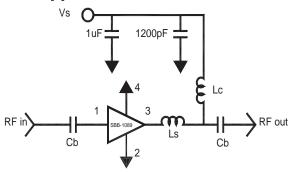




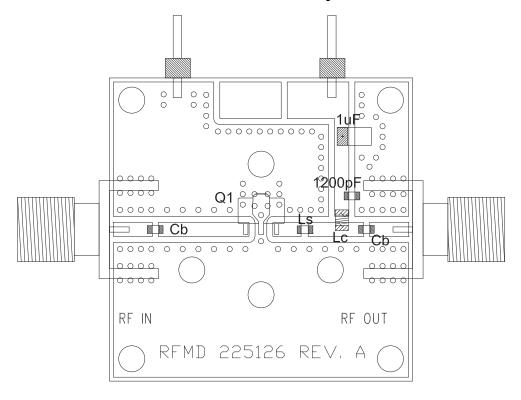
**Application Circuit Element Values** 

Reference Designator	Frequency (MHZ) 50 to 850		
СВ	8200 pF		
L <sub>C</sub>	1500nH 0805LS Coilcraft		
L <sub>S</sub>	2.7 nH Toko		

## **Application Schematic**



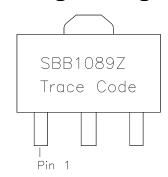
## **Evaluation Board Layout**



# **SBB1089Z**



## **Package Marking**



# **Ordering Information**

Ordering Code	Description
SBB1089Z	7" Reel with 1000 pieces
SBB1089ZSQ	Sample bag with 25 pieces
SBB1089ZSR	7" Reel with 100 pieces
SBB1089ZPCK1	50 MHz to 850 MHz PCBA with 5-piece sample bag